



## **MJE271G Information**



For Reference Only

Part Number MJE271G

Manufacturer ON Semiconductor

**Category** Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

**Description** TRANS PNP DARL 100V 2A TO-225

Package TO-225AA, TO-126-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

### **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









# **MJE271G Specifications**

Manufacturer Part Number	MJE271G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-225AA, TO-126-3
Series	-
Transistor Type	PNP - Darlington
Current - Collector (Ic) (Max)	2A
Voltage - Collector Emitter Breakdown (Max)	100V
Vce Saturation (Max) @ Ib, Ic	3V @ 1.2mA, 120mA
Current - Collector Cutoff (Max)	1mA
DC Current Gain (hFE) (Min) @ Ic, Vce	1500 @ 120mA, 10V
Power - Max	1.5W
Frequency - Transition	6MHz
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-225AA, TO-126-3
Supplier Device Package	TO-225AA
	Report errors?

### **MJE271G Guarantees**



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

## **MJE271G Payment Methods**



















# **MJE271G Shipping Methods**













If you have any question about MJE271G, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com